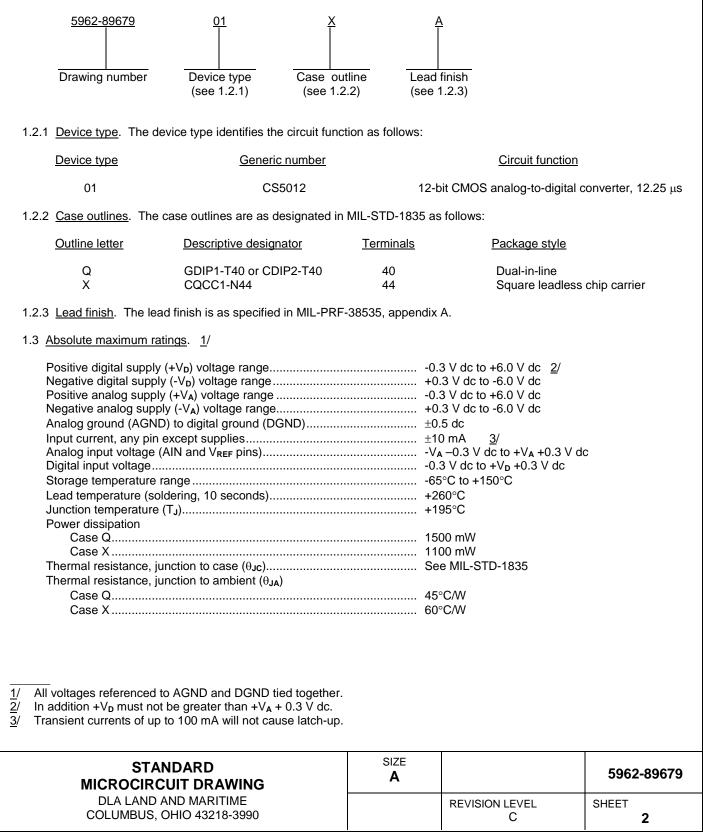
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REV SHEET REV SHEET REV STATUS OF SHEETS PMIC N/A				REV SHE PRE CHE	/ ET PAREI	D BY Rick C BY harles I	C 1	C 2	C	C	C	6 CC	7 DLA I DLUM	8 LAND IBUS,	9 AND , OHI0	10 0 MAF 0 432	11 RITIM 218-39	12 E 990	13	
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1. SCOPE	
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1.1 <u>Scope</u>. This drawing describes device requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A.

1.2 Part or Identifying Number (PIN). The complete PIN is as shown in the following example:



1.4 <u>Recommended operating conditions</u>. <u>1</u>/

Positive analog supply voltage $(+V_A)$	+4.5 V dc to +V _A $2/$ -4.5 V dc to -5.5 V dc +4.5 V dc to -5.5 V dc -4.5 V dc to -5.5 V dc 0 V dc 0 V dc -0.3 V dc to +0.8 V dc +2.0 V dc to +V _D
Unipolar mode Bipolar mode	

2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbooks</u>. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 -	Test Method Standard Microcircuits.
MIL-STD-1835 -	Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings. MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at https://assist.dla.mil/quicksearch/ or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

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3. REQUIREMENTS

3.1 <u>Item requirements</u>. The individual item requirements shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-PRF-38535 may be processed as QML product in accordance with the manufacturers approved program plan and qualifying activity approval in accordance with MIL-PRF-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect form, fit, or function of the device. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-PRF-38535 is required to identify when the QML flow option is used.

3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535, appendix A and herein.

3.2.1 <u>Case outlines</u>. The case outlines shall be in accordance with 1.2.2 herein.

3.2.2 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 1.

3.2.3 <u>Truth table</u>. The truth table shall be as specified on figure 2.

3.2.4 Block diagram. The block diagram shall be as specified on figure 3.

3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full ambient operating temperature range.

3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

3.5 <u>Marking</u>. Marking shall be in accordance with MIL-PRF-38535, appendix A. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device.

3.5.1 <u>Certification/compliance mark</u>. A compliance indicator "C" shall be marked on all non-JAN devices built in compliance to MIL-PRF-38535, appendix A. The compliance indicator "C" shall be replaced with a "Q" or "QML" certification mark in accordance with MIL-PRF-38535 to identify when the QML flow option is used.

3.6 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6 herein). The certificate of compliance submitted to DLA Land and Maritime -VA prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-PRF-38535, appendix A and the requirements herein.

3.7 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 <u>Notification of change</u>. Notification of change to DLA Land and Maritime -VA shall be required for any change that affects this drawing.

3.9 <u>Verification and review</u>. DLA Land and Maritime, DLA Land and Maritime's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

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	TAE	BLE I. Electrical performance char	acteristics.				
Test	Symbol	$Conditions \\ -55^{\circ}C \leq T_A \leq +125^{\circ}C$	Group A subgroups	Device type	Lin	nits	Unit
		unless otherwise specified			Min	Max	
Resolution for which no missing codes is guaranteed	RES	<u>1</u> /	1, 2, 3	01	12		Bits
Integral linearity error	INL	<u>1/, 2/</u>	1, 2, 3	01		±0.5	LSB
Differential linearity error	DNL	<u>1/, 2/</u>	1, 2, 3	01		±0.5	LSB
Full-scale error	FSE	<u>1</u> /, <u>2</u> /	1, 2, 3	01		±0.5	LSB
Full-scale error drift	dFSE/d _t	<u>1/, 2/, 3/, 4/</u>	2, 3	01		±0.25	LSB
Unipolar offset error	VOFF	<u>1/, 2/</u>	1, 2, 3	01		±0.5	LSB
Unipolar offset error drift	dVOFF/d _t	<u>1/, 2/, 3/, 4/</u>	2, 3	01		±0.25	LSB
Bipolar offset error	BOFF	<u>1/, 2/</u>	1, 2, 3	01		±0.5	LSB
Bipolar offset error drift	dBOFF/dt	<u>1/, 2/, 3/, 4/</u>	2, 3	01		±0.25	LSB
Bipolar negative full-scale error	BNFSE	<u>1/, 2/</u>	1, 2, 3	01		±0.5	LSB
Bipolar negative full-scale error drift	dBNFSE/ d _t	<u>1/, 2/, 3/, 4/</u>	2, 3	01		±0.25	LSB
Peak harmonic or spurious noise	S/PN	1 kHz input, full scale amplitude, bipolar mode <u>1/, 2</u> /	4, 5, 6	01	84		dB
		12 kHz input, full scale amplitude, bipolar mode <u>1/, 2</u> /			80		
Signal to noise ratio	S/(N+D)	1 kHz input, full scale amplitude, bipolar mode <u>1/, 2</u> /	4, 5, 6	01	72		dB
Analog input capacitance in fine charge mode	Cin	Unipolar mode, $T_A = +25^{\circ}C \underline{1}, \\ \underline{3}/$	4	01		375	pF
		Bipolar mode, $T_A = +25^{\circ}C \underline{1}/, \\ \underline{3}/$				220	
Digital input voltage (HOLD, CLKIN, CAL, INTRLV, BW, RST, BP/UP, AO, RD, CS)	Vih	<u>5</u> /, <u>6</u> /	1, 2, 3	01	2.0		V
	VIL					0.8	
Digital input current	l _{in}	<u>5</u> /, <u>6</u> /	1, 2, 3	01		±10	μΑ

See footnotes at end of table.

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		Electrical performance characteri		<u></u>			
Test	Symbol	$\begin{array}{c} Conditions \\ \textbf{-55^{\circ}C} \leq T_{A} \leq \textbf{+125^{\circ}C} \end{array}$	Group A subgroups	Device type	Lim	nits	Unit
	1	unless otherwise specified	!	'	Min	Max	
Digital output voltage ($D_0 - D_{15}$, SDATA, SCLK, EDC, EOT)	Vol	Logic "0", Ι _{SINK} = -1.6 mA <u>5</u> /, <u>6</u> /	1, 2, 3	01		0.4	V
	V _{он}	Logic "1", I _{SOURCE} = 100 μA <u>5</u> /, <u>6</u> /]		+V _D -1.0		
High impedance state output current	l _{oz}	Pins D ₀ to D ₁₅ only <u>5</u> /, <u>6</u> /	1, 2, 3	01		±10	μA
Conversion time	tc	<u>1/, 6/, 7/</u>	9, 10, 11	01		12.25	μs
Acquisition time	tacq	T _A = +25°C <u>1/, 2/, 3/, 8</u> /	9	01		3.75	μs
Throughput	^t рит	<u>1/, 2/, 6/</u>	9, 10, 11	01	62.5	 	kHz
Positive analog supply current	I _{A+}	$+V_{A}, +V_{D} = 5.5 V,$ $-V_{A}, -V_{D} = -5.5 V \underline{6}/, \underline{9}/$	1, 2, 3	01		19.0	mA
Negative analog supply current	I _{A-}	$+V_{A}, +V_{D} = 5.5 V,$ $-V_{A}, -V_{D} = -5.5 V \underline{6}/,\underline{9}/$	1, 2, 3	01		19.0	mA
Positive digital supply current	I _{D+}	$+V_A$, $+V_D = 5.5 V$, $-V_A$, $-V_D = -5.5 V 6/, 9/$	1, 2, 3	01		6.0	mA
Negative digital supply current	I _{D-}	$+V_A, +V_D = 5.5 V,$ $-V_A, -V_D = -5.5 V \underline{6}/, \underline{9}/$	1, 2, 3	01		6.0	mA
Master clock frequency <u>10</u> /	fс∟к	Internally generated, CLKIN = 0 V dc, $+V_D$, $+V_A = 4.5$ V, $-V_D - V_A = -4.5$ V, $T_A = -55^{\circ}C$	11	01	1.75		MHz
HOLD pulse width	t _{HPW}	(see figure 4) <u>5</u> /, <u>6</u> /, <u>11</u> /	9, 10, 11	01	1/f _{с∟к} +50	tc	ns
Data delay time	t _{DD}	(see figure 4) <u>5/, 6/, 11/</u>	9, 10, 11	01		100	ns
EOC pulse width	t _{EPW}	(see figure 4) <u>5</u> /, <u>6</u> /, <u>11</u> /	9, 10, 11	01	4/f _{cLк} -20		ns
CAL, INTRLV to CS low setup time	tcs	(see figure 5) <u>5</u> /, <u>6</u> /, <u>11</u> /	9, 10, 11	01	20		ns
A0 to $\overline{\text{CS}}$ and $\overline{\text{RD}}$ low setup time	t _{AS}	(see figure 5) <u>5</u> /, <u>6</u> /, <u>11</u> /	9, 10, 11	01	20		ns
$\overline{\text{CS}}$ or $\overline{\text{RD}}$ High to A0 invalid hold time	t _{АН}	(see figure 5) <u>5</u> /, <u>6</u> /, <u>11</u> /	9, 10, 11	01	50		ns

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TABLE I. Electrical performance characteristics - continued.

See footnotes at end of table.

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			<u></u>				
Test	Symbol	$Conditions \\ \textbf{-55^{\circ}C} \leq T_{A} \leq \textbf{+125^{\circ}C}$	Group A subgroups	Device type	Lin	nits	Unit
		unless otherwise specified			Min	Max	
CS High to CAL, INTRLV invalid hold time	tсн	(see figure 5) <u>5</u> /, <u>6</u> /, <u>11</u> /	9, 10, 11	01	50		ns
$\overline{\text{CS}}$ low to data valid access time	t _{CA}	RD = logic "0", (see figure 5) <u>5/, 6/, 11</u> /	9, 10, 11	01		250	ns
\overrightarrow{RD} low to data valid access time	t _{RA}	CS = logic "0", (see figure 5) <u>5/, 6/, 11</u> /	9, 10, 11	01		250	ns
Output float delay	t _{FD}	(see figure 5) <u>5</u> /, <u>6</u> /, <u>11</u> /	9, 10, 11	01		250	ns
SDATA to SCLK rising setup time	tss	(see figure 6) <u>5</u> /, <u>6</u> /, <u>11</u> /	9, 10, 11	01	2/f _{cLк} -50		ns
SCLK rising to SDATA hold time	tsн	(see figure 6) <u>5</u> /, <u>6</u> /, <u>11</u> /	9, 10, 11	01	2/f _{с∟к} -100		ns

TABLE I. <u>Electrical performance characteristics</u> - continued.

1/ +V_A, +V_D = +5.0 V; -V_A, -V_D = -5.0 V; V_{REF} = +2.5 V dc or +4.5 V dc; f_{CLK} = 4 MHz; Analog source impedance = 200 Ω ; Error tests are done after calibration at the temperature of interest.

2/ Synchronous sampling mode (EOT connected to HOLD), interleave disabled.

- 3/ This parameter shall be measured only for initial characterization and after process or design changes which may affect this parameter.
- $\underline{4}$ Total drift over -55°C to +125°C since calibration at power-up at +25°C.
- 5/ +V_A, +V_D = +5.0 V dc ±10%; -V_A, -V_D = -5.0 V dc ±10%.
- $\underline{6}$ This parameter is guaranteed, if not tested, at T_A = +25°C. This parameter is tested at T_A = -55°C and +125°C.
- $\underline{7}$ Measured from falling transition on $\overline{\text{HOLD}}$ to falling transition on $\overline{\text{EOC}}$.
- 8/ Acquisition time is the time allowed by the converter for acquisition of the input voltage prior to conversion.
- <u>9</u>/ All outputs unloaded; All inputs swinging between $+V_{D}$ and 0 V dc.
- <u>10</u>/ Externally supplied maximum clock frequency is 4 MHz. Analog parametric measurements are done with the maximum external clock (see footnote <u>1</u>/).
- <u>11</u>/ Inputs: logic "0" = 0 V, logic "1" = $+V_D$; C_L = 50 pF.

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Device twee	0.	4
Device types	0.	
Case outlines	Q	Х
Terminal number	Terminal	symbol
1	HOLD	HOLD
2	Do	Do
3 4	D₁ D₂	D1 D2
5	D ₂ D ₃	D ₂ D ₃
6	D4	D4
7	D₅	D5
8	D ₆	D ₆
9 10	D7 DGND	NC D7
11	+V _D	DGND
12	D ₈	+V _D
13	D ₉	NC
14 15	D ₁₀ D ₁₁	D ₈ NC
16	D ₁₁ D ₁₂	D ₉
17	D ₁₃	D ₁₀
18	D ₁₄	D ₁₁
19 20	D₁₅ CLKIN	D ₁₂ D ₁₃
20		D13 D14
22		D ₁₄ D ₁₅
23	A0	
24	BP/UP	CS
25	+VA	RD
26	AIN	AO
27	AGND	BP/UP
28	VREF	+Va
29	REFBUF	AIN
30 31	-V₄ TST	AGND VREF
32	RST	REFBUF
33	BW	NC
34	INTRLV	-V _A
35	CAL	TST
36 37	-V₀ EOT	RST BW
38	EOC	INTRLV
39	SCLK	CAL
40	SDATA	-V _D
41		EOT
42		EOC
43 44		SCLK SDATA

NC = Not connected

FIGURE 1. Terminal connections.

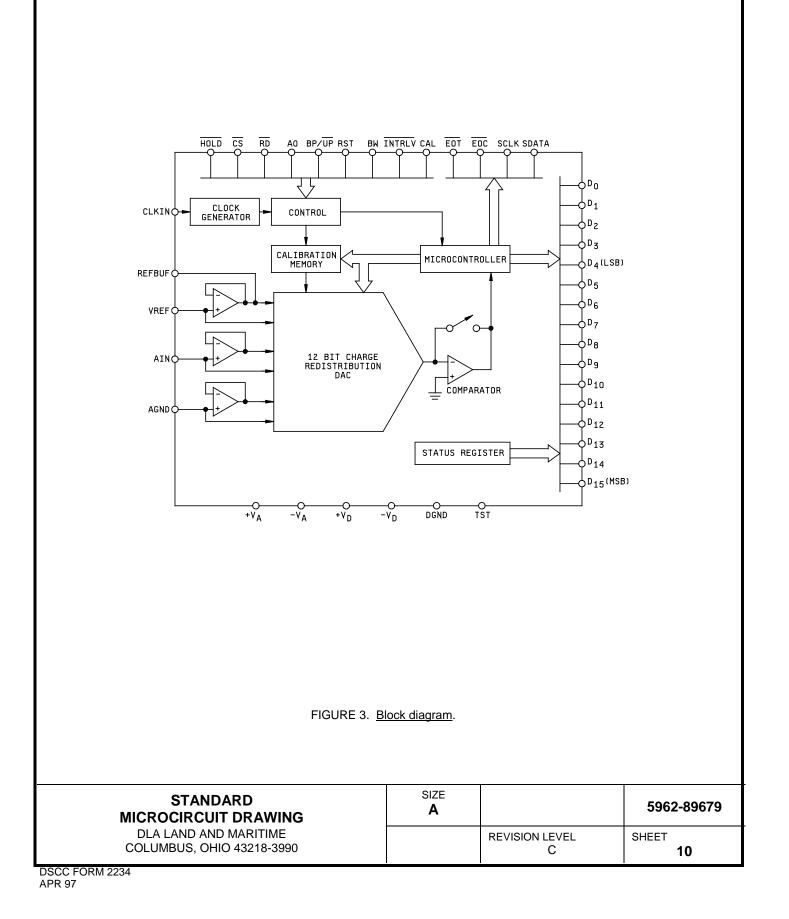
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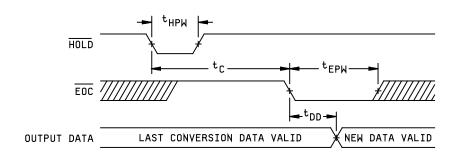
Function	HOLD	CS	CAL	INTRLV	RD	A0	RST
Hold and start convert	\downarrow	Х	Х	Х	Х	*	0
Initiate burst calibration	Х	0	1	Х	Х	*	0
Stop burst cal and begin track	1	0	0	Х	Х	*	0
Initiate interleave calibration	Х	0	Х	0	Х	*	0
Terminate interleave cal	Х	0	Х	1	Х	*	0
Read output data	Х	0	Х	Х	0	1	0
Read status register	1	0	Х	Х	0	0	0
High impedance data bus	Х	1	Х	Х	Х	*	Х
High impedance data bus	Х	Х	Х	Х	1	*	Х
Reset	Х	Х	Х	Х	Х	Х	1
Reset	0	0	Х	Х	Х	0	Х

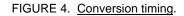
* The status of A0 is not critical to the operation specified. However A0 should not be low with \overline{CS} AND \overline{HOLD} low, or a software reset will result.

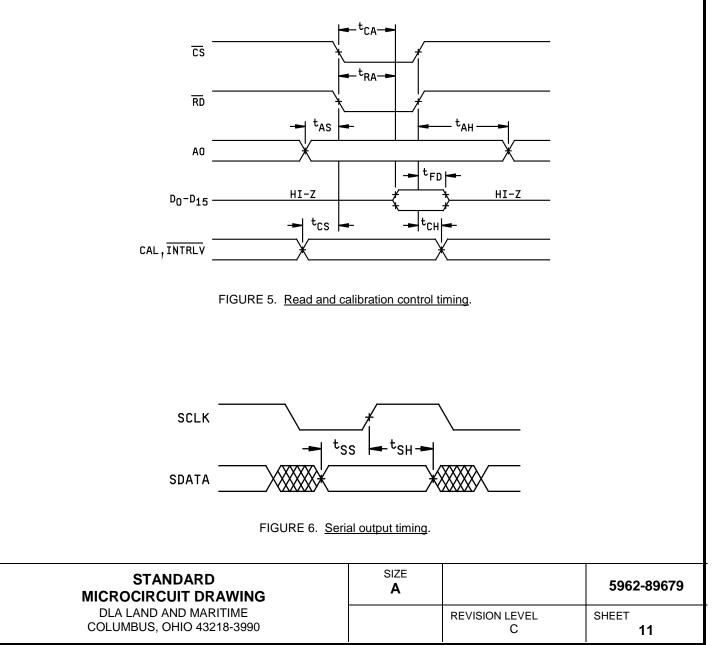
FIGURE 2. Truth table.

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4. VERIFICATION

4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

- a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}C$, minimum.
- b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

	n
MIL-STD-883 test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)
Interim electrical parameters (method 5004)	1, 4
Final electrical test parameters (method 5004)	1*, 2, 3, 4, 5, 6, 10, 11
Group A test requirements (method 5005)	1, 2, 3, 4, 5, 6, 9**, 10, 11
Groups C and D end-point electrical parameters (method 5005)	2, 3

TABLE II. Electrical test requirements.

* PDA applies to subgroup 1.

** Subgroup 9 is guaranteed if not tested.

4.3 <u>Quality conformance inspection</u>. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 7 and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.

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4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535, appendix A.

6. NOTES

6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractorprepared specification or drawing.

6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.4 <u>Record of users</u>. Military and industrial users shall inform DLA Land and Maritime when a system application requires configuration control and the applicable SMD to that system. DLA Land and Maritime will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DLA Land and Maritime -VA, telephone (614) 692-0544.

6.5 <u>Comments</u>. Comments on this drawing should be directed to DLA Land and Maritime -VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0540.

6.6 <u>Approved sources of supply</u>. Approved sources of supply are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DLA Land and Maritime -VA.

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DATE: 12-11-27

Approved sources of supply for SMD 5962-89679 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DLA Land and Maritime -VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DLA Land and Maritime maintains an online database of all current sources of supply at http://www.landandmaritime.dla.mil/Programs/Smcr/.

Standard	Vendor	Vendor
microcircuit drawing	CAGE	similar
PIN <u>1</u> /	number	PIN <u>2</u> /
5962-8967901QC	68911	SEI5012-TD12B
	3RNH0	5012-TD12B
5962-8967901XC	68911	SEI5012-TE12B
	3RNH0	5012-TE12B

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE <u>number</u>	Vendor name and address
68911	Maxwell Technologies Electronics Components Group, Inc. 9244 Balboa Ave. San Diego, CA 92123
3RNH0	XTREME Semiconductor 2801 Oakmont Drive, Bldg. A, Suite 700 Round Rock, TX 78664

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.